









	<h2 style="color: #C00000;">IPB100N06S3L-04</h2>	
	<b>Hersteller-Teilenummer:</b>	IPB100N06S3L-04
	<b>Hersteller / Marke:</b>	International Rectifier (Infineon Technologies)
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 55V 100A TO-263
<b>Datenblätter:</b>	 <a href="#">IPB100N06S3L-04.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 14513 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen	
Teilenummer	IPB100N06S3L-04
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 55V 100A TO-263
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	14513 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-3-2
Verlustleistung (max)	214W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	55V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	100A (Tc)
Rds On (Max) @ Id, Vgs	3.5 mOhm @ 80A, 10V
VGS (th) (Max) @ Id	2.2V @ 150µA
Gate Charge (Qg) (Max) @ Vgs	362nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	17270pF @ 25V
Verpackung	Tape & Reel (TR)

IPB100N06S3L-04 ist neu im Original. Suche IPB100N06S3L-04 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB100N06S3L-04 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB100N06S3L-04: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IPB100N08S2L07ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 75V 100A TO263-3</p>	 <p><b>IPB100N06S3-03</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A D2PAK</p>	 <p><b>IPB100N08S2-07</b> INFINEO IPB100N08S2-07 INFINEO</p>	 <p><b>IPB100N10S3-05</b> International Rectifier (Infineon Technologies) IPB100N10S3-05 Infineon Technologies</p>
 <p><b>IPB100N06S3-04</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO-263</p>	 <p><b>IPB100N08S2L-07</b>   IPB100N08S2L-07  </p>	 <p><b>IPB100N06S2L05ATMA2</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO263-3</p>	 <p><b>IPB100N08S207ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 75V 100A TO263-3</p>

**heiße Teile** (Mehr)

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|------------------|-------------------|-------------------|-------------------|-------------------|
| ⊗ IPB090N06N3    | ↔ IPB090N06N3G    | ⇒ IPB091N06NG     | D IPB093N04LG     | ↔ IPB096N03L      |
| ⊣ IPB096N03LG    | ⊗ IPB097N08N3     | D IPB097N08N3G    | ⇒ IPB09N03        | ↔ IPB09N03LA      |
| ⊗ IPB09N03LAG    | ⊣ IPB09N03LAT     | ⊗ IPB100N04S2-04  | ↔ IPB100N04S2L-03 | ↔ IPB100N04S3     |
| D IPB100N04S3-03 | ⊗ IPB100N04S3-03M | ⊣ IPB100N04S4-02D | ⊗ IPB100N04S4-03D | ↔ IPB100N04S4-H2  |
| ⇒ IPB100N06S2-05 | ↔ IPB100N06S2L-05 | ⊗ IPB100N06S3-03  | ⊣ IPB100N06S3-04  | ↔ IPB100N06S3L-03 |
| ↔ IPB100N08S2-07 | ⇒ IPB100N08S2L-07 | D IPB100N10S3-05  | ⊗ IPB107N20N3G    | ⊣ IPB10N03L       |
| ⊗ IPB10N03LB     | D IPB10N03LBG     | ⇒ IPB110N06L      | ↔ IPB110N06LG     | ↔ IPB114N03L      |
| ⊣ IPB114N03LG    | ⊗ IPB11N03LAG     | ↔ IPB11N60S5      | ⇒ IPB120N04S3-02  | ↔ IPB120N04S4-01  |
| ⊗ IPB120N04S4-02 | ⊣ IPB120N06NG     | ⊗ IPB120N06S4     | D IPB120N06S4-02  | ↔ IPB120N06S4-03  |
| ↔ IPB120N06S4-H1 | ⊗ IPB120P04L03    | ⊣ IPB120P04P4L-03 | ⊗ IPB123N10N3     | ↔ IPB123N10N3G    |